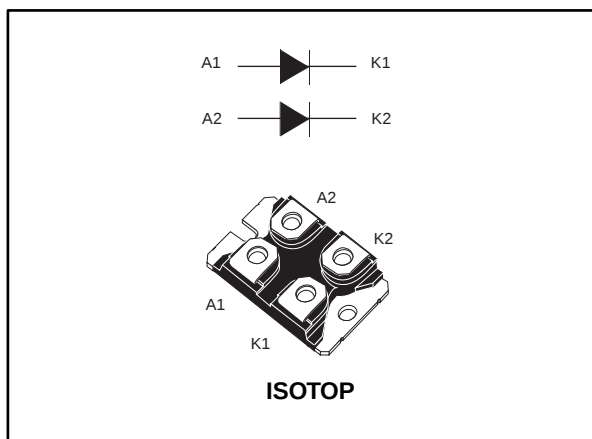


## High voltage power Schottky rectifier

Datasheet - production data



### Description

This high voltage Schottky rectifier is suited for high frequency switch mode power supplies.

Packaged in ISOTOP, this device is intended for use in the secondary rectification of applications.

Table 1: Device summary

| Symbol       | Value     |
|--------------|-----------|
| $I_{F(AV)}$  | 2 x 100 A |
| $V_{RRM}$    | 170 V     |
| $T_j$ (max.) | 150 °C    |
| $V_F$ (max.) | 0.63 V    |

### Features

- Negligible switching losses
- Avalanche rated
- Low leakage current
- Good trade-off between leakage current and forward voltage drop
- Insulated package ISOTOP:
  - Insulated voltage: 2500  $V_{RMS}$
  - Capacitance: 45 pF

# 1 Characteristics

**Table 2: Absolute ratings (limiting values, per diode at  $T_{amb} = 25\text{ °C}$ , unless otherwise specified)**

| Symbol              | Parameter                                             |                                                |           | Value       | Unit |
|---------------------|-------------------------------------------------------|------------------------------------------------|-----------|-------------|------|
| V <sub>RRM</sub>    | Repetitive peak reverse voltage                       |                                                |           | 170         | V    |
| I <sub>F(RMS)</sub> | Forward rms current                                   |                                                |           | 200         | A    |
| I <sub>F(AV)</sub>  | Average forward current, δ = 0.5                      | T <sub>C</sub> = 105 °C                        | Per diode | 100         | A    |
| I <sub>FSM</sub>    | Surge non repetitive forward current                  | t <sub>p</sub> = 10 ms sinusoidal              |           | 700         | A    |
| P <sub>ARM</sub>    | Repetitive peak avalanche power                       | t <sub>p</sub> = 10 μs T <sub>j</sub> = 125 °C |           | 7400        | W    |
| T <sub>stg</sub>    | Storage temperature range                             |                                                |           | -55 to +150 | °C   |
| T <sub>j</sub>      | Maximum operating junction temperature <sup>(1)</sup> |                                                |           | 150         | °C   |

**Notes:**

<sup>(1)</sup> $(dP_{tot}/dT_J) < (1/R_{th(j-a)})$  condition to avoid thermal runaway for a diode on its own heatsink.

**Table 3: Thermal parameters**

| Symbol        | Parameter                   |           | Maximum values | Unit |
|---------------|-----------------------------|-----------|----------------|------|
| $R_{th(j-c)}$ | Junction to case            | Per diode | 0.52           | °C/W |
|               |                             | Total     | 0.31           |      |
| $R_{th(c)}$   | Coupling thermal resistance |           | 0.1            |      |

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_J (\text{diode1}) = P_{(\text{diode1})} \times R_{th(j-c)} (\text{per diode}) + P_{(\text{diode2})} \times R_{th(c)}$$

**Table 4: Static electrical characteristics**

| Symbol      | Parameter               | Test conditions       |                      | Min. | Typ. | Max.  | Unit          |
|-------------|-------------------------|-----------------------|----------------------|------|------|-------|---------------|
| $I_R^{(1)}$ | Reverse leakage current | $T_J = 25\text{ °C}$  | $V_R = V_{RRM}$      | -    |      | 200   | $\mu\text{A}$ |
|             |                         | $T_J = 125\text{ °C}$ |                      | -    | 30   | 100   | mA            |
| $V_F^{(2)}$ | Forward voltage drop    | $T_J = 25\text{ °C}$  | $I_F = 100\text{ A}$ | -    |      | 0.85  | V             |
|             |                         | $T_J = 150\text{ °C}$ |                      | -    | 0.63 | 0.68  |               |
|             |                         | $T_J = 25\text{ °C}$  | $I_F = 200\text{ A}$ | -    |      | 0.975 |               |
|             |                         | $T_J = 150\text{ °C}$ |                      | -    | 0.78 | 0.86  |               |

**Notes:**

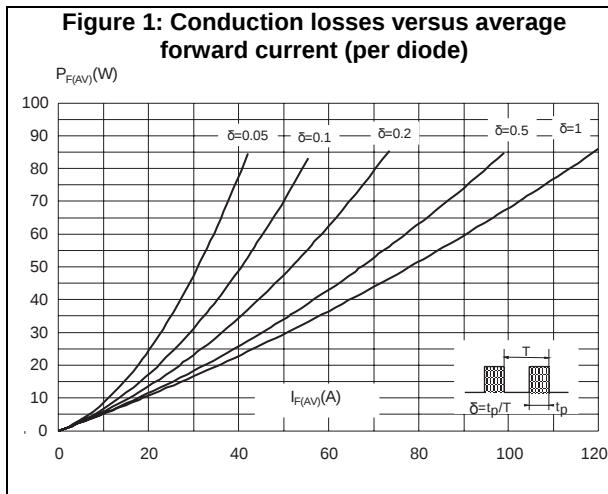
<sup>(1)</sup>Pulse test:  $t_p = 5\text{ ms}$ ,  $\delta < 2\%$

<sup>(2)</sup>Pulse test:  $t_p = 380\text{ }\mu\text{s}$ ,  $\delta < 2\%$

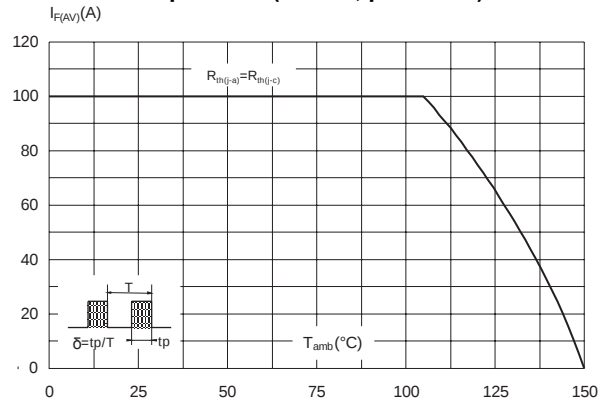
To evaluate the maximum conduction losses, use the following equation:

$$P = 0.5 \times I_{F(AV)} + 0.0018 \times I_{F(RMS)}^2$$

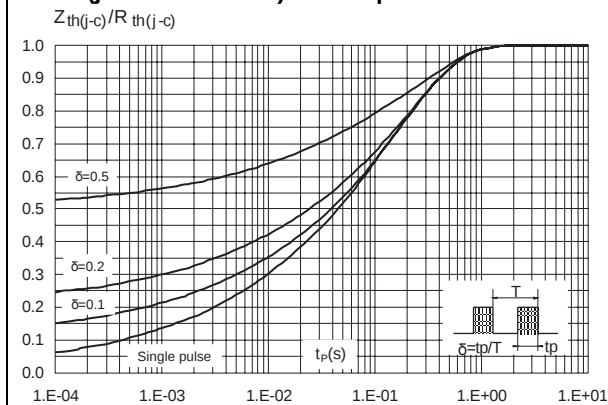
## 1.1 Characteristics (curves)



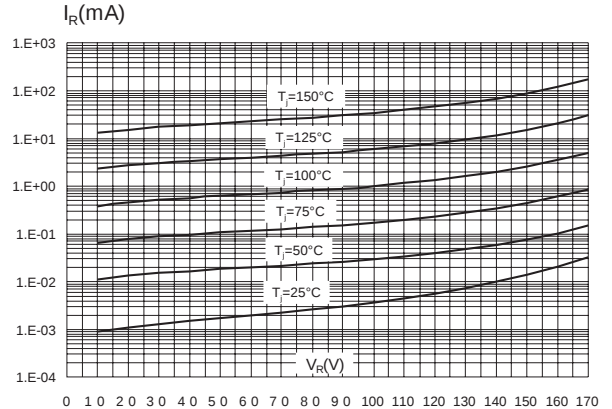
**Figure 2: Average forward current versus ambient temperature ( $\delta = 0.5$ , per diode)**



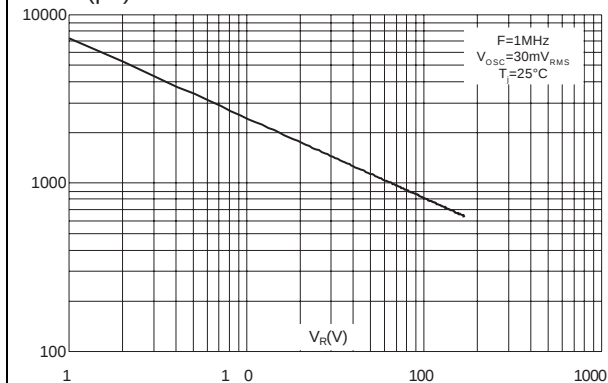
**Figure 3: Relative variation of thermal impedance (junction to case) versus pulse duration**



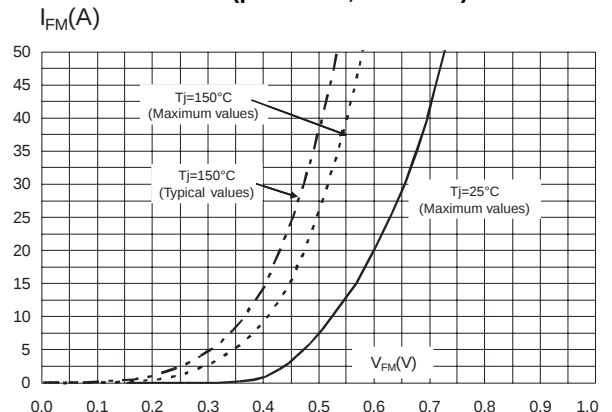
**Figure 4: Reverse leakage current versus reverse voltage applied (typical values, per diode)**



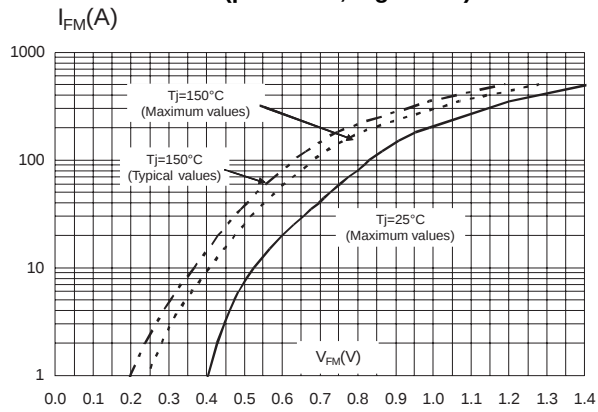
**Figure 5: Junction capacitance versus reverse voltage applied (typical values, per diode)**



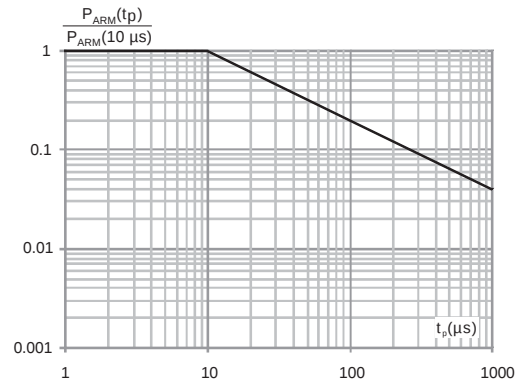
**Figure 6: Forward voltage drop versus forward current (per diode, low level)**



**Figure 7: Forward voltage drop versus forward current (per diode, high level)**



**Figure 8: Normalized avalanche power derating versus pulse duration**



## 2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: [www.st.com](http://www.st.com). ECOPACK® is an ST trademark.

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)
- Recommended torque value: 1.3 N·m
- Maximum torque value: 1.5 N·m

STMicroelectronics strongly recommends the use of the screws delivered with this product.

The use of any other screws is entirely at the user's own risk and will invalidate the warranty.

### 2.1 ISOTOP package information

Figure 9: ISOTOP package outline

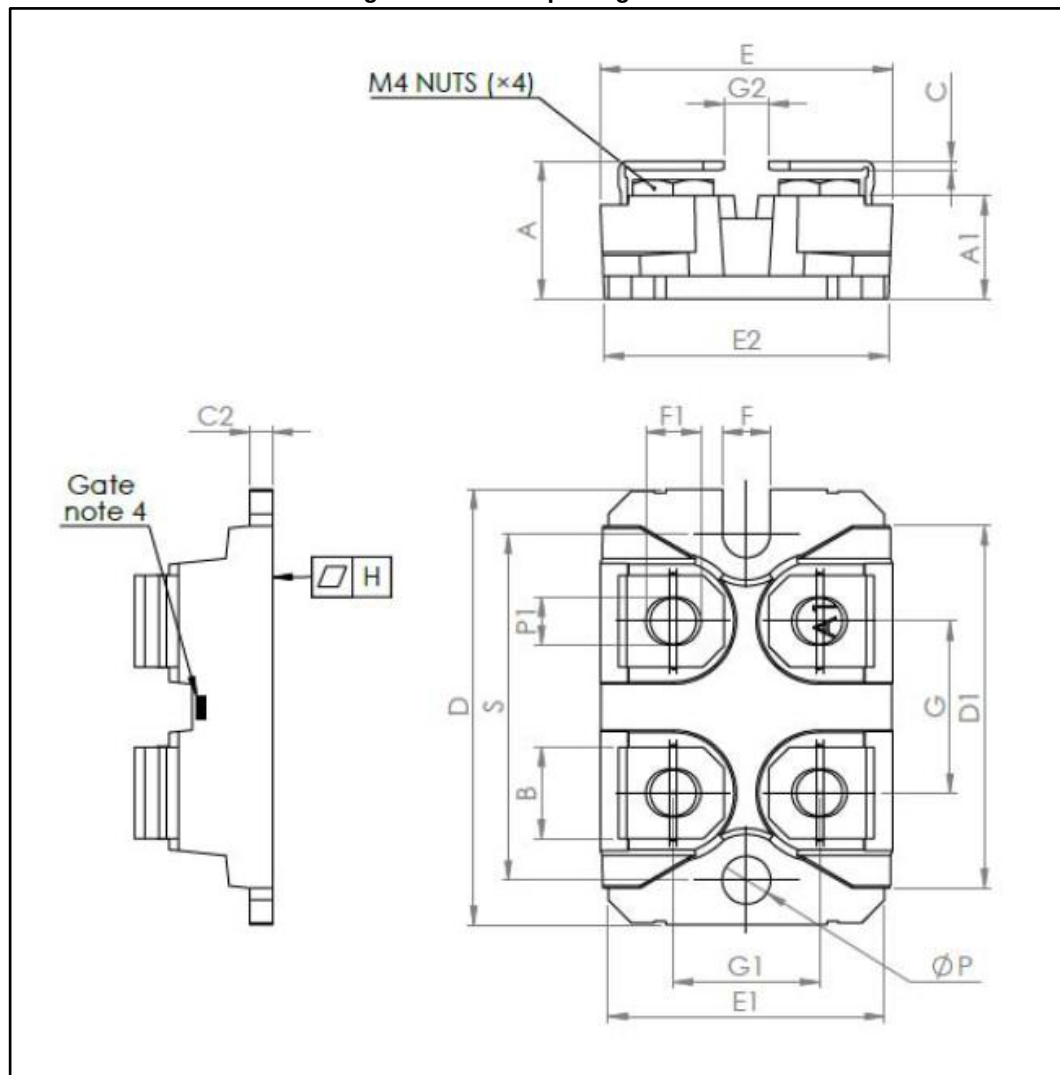


Table 5: ISOTOP package mechanical data

| Ref.   | Dimensions  |       |        |       |
|--------|-------------|-------|--------|-------|
|        | Millimeters |       | Inches |       |
|        | Min.        | Max.  | Min.   | Max.  |
| A      | 11.80       | 12.20 | 0.465  | 0.480 |
| A1     | 8.90        | 9.10  | 0.350  | 0.358 |
| B      | 7.80        | 8.20  | 0.307  | 0.323 |
| C      | 0.75        | 0.85  | 0.030  | 0.033 |
| C2     | 1.95        | 2.05  | 0.077  | 0.081 |
| D      | 37.80       | 38.20 | 1.488  | 1.504 |
| D1     | 31.50       | 31.70 | 1.240  | 1.248 |
| E      | 25.15       | 25.50 | 0.990  | 1.004 |
| E1     | 23.85       | 24.15 | 0.939  | 0.951 |
| E2     | 24.80       |       | 0.976  |       |
| G      | 14.90       | 15.10 | 0.587  | 0.594 |
| G1     | 12.60       | 12.80 | 0.496  | 0.504 |
| G2     | 3.50        | 4.30  | 0.138  | 0.169 |
| F      | 4.10        | 4.30  | 0.161  | 0.169 |
| F1     | 4.60        | 5     | 0.181  | 0.197 |
| H      | -0.05       | 0.1   | -0.002 | 0.004 |
| Diam P | 4           | 4.30  | 0.157  | 0.169 |
| P1     | 4           | 4.40  | 0.157  | 0.173 |
| S      | 30.10       | 30.30 | 1.185  | 1.193 |

### 3 Ordering information

Table 6: Ordering information

| Order code    | Marking       | Package | Weight                   | Base qty.           | Delivery mode |
|---------------|---------------|---------|--------------------------|---------------------|---------------|
| STPS200170TV1 | STPS200170TV1 | ISOTOP  | 27 g<br>(without screws) | 10<br>(with screws) | Tube          |

### 4 Revision history

Table 7: Document revision history

| Date        | Revision | Changes                                                                                                                                                                                          |
|-------------|----------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 14-Nov-2005 | 1        | First issue.                                                                                                                                                                                     |
| 09-Sep-2011 | 2        | Updated $V_F$ max at $T_j = 25\text{ °C}$ and $I_F = 100\text{ A}$ to 0.85 V.                                                                                                                    |
| 12-Feb-2018 | 3        | Updated <a href="#">Table 2: "Absolute ratings (limiting values, per diode at <math>T_{amb} = 25\text{ °C}</math>, unless otherwise specified)"</a> and the new PARM curve at 10 $\mu\text{s}$ . |

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